



650V SiC Schottky Diode

VDC	650 V
Q _c	21 nC
I _F	8 A
T _j ,max	175 °C

Amp+[™] Features

- Unipolar rectifier with surge current
- Zero reverse recovery current
- · Fast, temperature-independent switching
- Avalanche tested to 54mJ*

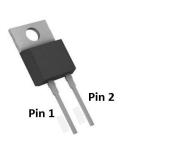
Amp+[™] Benefits

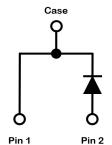
- Near zero switching loss
- Higher efficiency
- Smaller heat sink
- Easy to parallel

Amp+[™] Applications

- Switch mode power supplies, UPS
- Power factor correction
- Output rectification
- General Purpose

Package





Part #	Package	Marking
GP3D008A065A	TO-220-2L	3D008A065



Maximum Ratings, at T_i=25 °C, unless otherwise specified

Characteristics	Symbol	Conditions	Values	Unit	
	I _{F**}	T _C =25 °C, T _j =175 °C	27		
Continuous forward current		T _C =125 °C, T _j =175 °C	14	A	
		T _C =150 °C, T _j =175 °C	9		
Surge non-repetitive forward current		$T_{\rm C}$ =25 °C, $t_{\rm p}$ =8.3 ms	70	- A	
sine halfwave	I _{FSM}	T _C =110 °C, t _p =8.3 ms	60		
Non-repetitive peak forward current	I _{F,max}	T _C =25 °C, t _p =10 μs	580	Α	
:24	∫i²dt	T _C =25 °C, t _p =8.3 ms	20	A2-	
$ i^2t $ value		T _C =110 °C, t _p =8.3 ms	15	- A ² s	
Repetitive peak reverse voltage	V_{RRM}	T _j =25 °C	650	V	
Diode dv/dt ruggedness	dv/dt	Turn-on slew rate, repetitive	200	V/ns	
Power dissipation	P _{tot**}	T _C =25 °C	102	W	
Operating junction & storage temperature	T _j , T _{storage}	Continuous	-55175	°C	
Soldering temperature	T _{solder}	Wave soldering leads	260	°C	
Mounting torque		M3 Screw	1	N-m	

Notes

^{*} EAS of 54 mJ is based on starting Tj = 25° C, L = 1.0 mH, IAS = 10.39 A, V = 50 V.

^{**} Typical Rth_{JC} used

Electrical Characteristics, at T_j=25 °C, unless otherwise specified

Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	Oilit
DC blocking voltage	V _{DC}	T _j =25 °C	650	-	-	V
Diode forward voltage	V _F	I _F =8A, T _j =25 °C	-	1.45	1.60	V
		I _F =8A, T _j =125 °C	-	1.57	-	
		I _F =8A, T _j =175 °C	-	1.69	2.20	
Reverse current	I _R	V _R =650V, T _j =25 °C	-	1	20	μΑ
		V _R =650V, T _j =125 °C	-	8	-	
		V _R =650V, T _j =175 °C	-	31	200	
Total capacitive charge	Q _C	V _R =400V, T _j =25 °C	-	21	-	nC
Total capacitance	С	V _R =1V, f=1 MHz	-	336	-	pF
		V _R =200V, f=1 MHz	-	41	-	
		V _R =400V, f=1 MHz	-	34	-	

Thermal Characteristics

Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	Oilit
Thermal resistance, junction-case	R _{thJC}	-	-	1.48	1.82	°C/W

Typical Performance

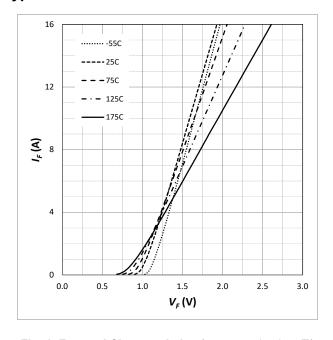


Fig. 1 Forward Characteristics (parameterized on T_i)

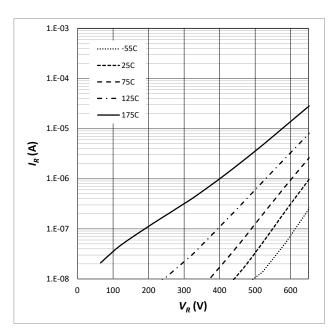
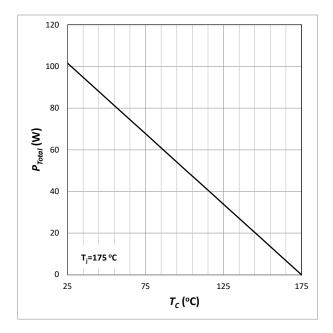


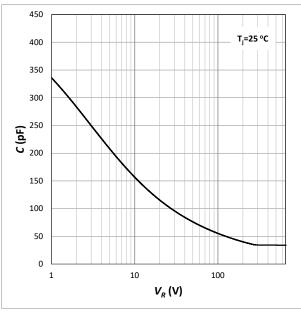
Fig. 2 Reverse Characteristics (parameterized on T_i)



140 Duty cycle **-**100% 120 100 80 /_F(A) 60 40 20 T_i=175 °C 0 105 125 25 45 65 145 165 T_c (°C)

Fig. 3 Power Derating

Fig. 4 Current Derating



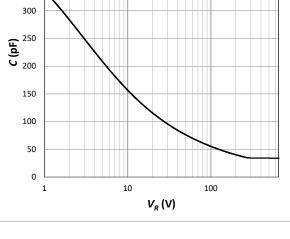


Fig. 5 Capacitance

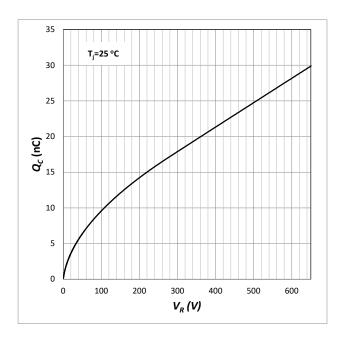
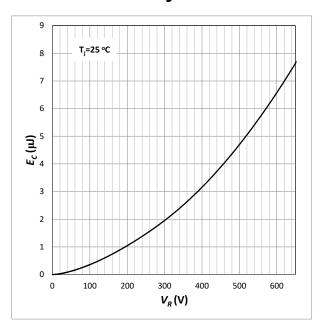


Fig. 6 Capacitive Charge



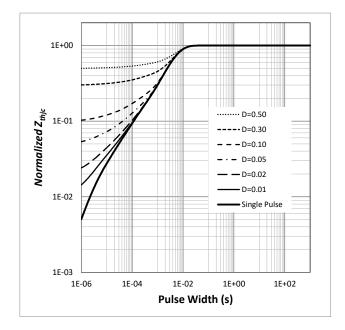
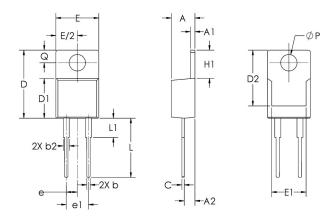


Fig. 7 Typical Capacitance Stored Energy

Fig. 8 Transient Thermal Impedance

Package Dimensions TO-220-2L



Sym	Millimeters		Inches		
Sym	Min	Max	Min	Max	
Α	3.56	4.83	0.140	0.190	
A1	0.51	1.40	0.020	0.055	
A2	2.03	2.92	0.080	0.115	
b	0.38	1.02	0.015	0.040	
b2	1.02	1.78	0.040	0.070	
С	0.36	0.76	0.014	0.030	
D	14.22	16.51	0.560	0.650	
D1	8.38	9.40	0.330	0.370	
D2	12.19	13.13	0.480	0.517	
Е	9.65	10.67	0.380	0.420	
E1	6.86	8.89	0.270	0.350	
е	2.54	BSC	.100	BSC	
e1	5.08	5.08 BSC		BSC	
H1	5.84	6.86	0.230	0.270	
L	12.57	14.73	0.495	0.580	
L1	3.60	6.35	0.142	0.250	
ØP	3.53	4.09	0.139	0.161	
Q	2.54	3.43	0.100	0.135	

Amp +™

GP3D008A065A

Notes

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented March, 2013. RoHS Declarations for this product can be obtained from the Product Documentation sections of www.SemiQ.com.

REACh Compliance

REACh substances of high concern (SVHC) information is available for this product. Since the European Chemicals Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact our office at SemiQ Headquarters in Lake Forest, California to insure you get the most up-to-date REACh SVHC Declaration. REACh banned substance information (REACh Article 67) is also available upon request.

SemiQ Inc., reserves the right to make changes to the product specifications and data in this document without notice. SemiQ products are sold pursuant to SemiQ's terms and conditions of sale in place at the time of order acknowledgement.

This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, or air traffic control.

SemiQ makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SemiQ assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using SemiQ products.

To obtain additional technical information or to place an order for this product, please contact us. The information in this datasheet is provided by SemiQ. SemiQ reserves the right to make changes, corrections, modifications, and improvements of datasheet without notice.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

SemiQ:

GP3D008A065A